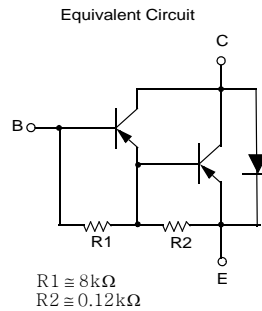
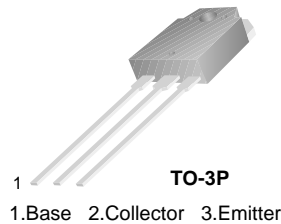


TIP145 / TIP146 / TIP147

PNP Epitaxial Silicon Darlington Transistor

Features

- Monolithic Construction With Built In Base-Emitter Shunt Resistors
- High DC Current Gain : $h_{FE} = 1000$ @ $V_{CE} = -4V$, $I_C = -5A$ (Min.)
- Industrial Use
- Complement to TIP140/141/142



Absolute Maximum Ratings* $T_A = 25^\circ C$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage : TIP145	- 60	V
	: TIP146	- 80	V
	: TIP147	- 100	V
V_{CEO}	Collector-Emitter Voltage : TIP145	- 60	V
	: TIP146	- 80	V
	: TIP147	- 100	V
V_{EBO}	Emitter-Base Voltage	- 5	V
I_C	Collector Current (DC)	- 10	A
I_{CP}	Collector Current (Pulse)	- 15	A
I_B	Base Current (DC)	- 0.5	A
P_C	Collector Dissipation ($T_C=25^\circ C$)	125	W
T_J	Junction Temperature	150	$^\circ C$
T_{STG}	Storage Temperature	- 65 to +150	$^\circ C$

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Electrical Characteristics* $T_A=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
$V_{\text{CEO(sus)}}$	Collector-Emitter Sustaining Voltage	$I_C = -30\text{mA}, I_B = 0$	- 60 - 80 - 100			V V V
	: TIP145					
	: TIP146 : TIP147					
I_{CEO}	Collector Cut-off Current	$V_{\text{CE}} = -30\text{V}, I_B = 0$ $V_{\text{CE}} = -40\text{V}, I_B = 0$ $V_{\text{CE}} = -50\text{V}, I_B = 0$			- 2 - 2 - 2	mA mA mA
	: TIP145					
	: TIP146 : TIP147					
I_{CBO}	Collector Cut-off Current	$V_{\text{CB}} = -60\text{V}, I_E = 0$ $V_{\text{CB}} = -80\text{V}, I_E = 0$ $V_{\text{CB}} = -100\text{V}, I_E = 0$			- 1 - 1 - 1	mA mA mA
	: TIP145					
	: TIP146 : TIP147					
I_{EBO}	Emitter Cut-off Current	$V_{\text{BE}} = -5\text{V}, I_C = 0$			- 2	mA
h_{FE}	DC Current Gain	$V_{\text{CE}} = -4\text{V}, I_C = -5\text{A}$	1000			
		$V_{\text{CE}} = -4\text{V}, I_C = -10\text{A}$	500			
$V_{\text{CE(sat)}}$	Collector-Emitter Saturation Voltage	$I_C = -5\text{A}, I_B = -10\text{mA}$			- 2	V
		$I_C = -10\text{A}, I_B = -40\text{mA}$			- 3	V
$V_{\text{BE(sat)}}$	Base-Emitter Saturation Voltage	$I_C = -10\text{A}, I_B = -40\text{mA}$			- 3.5	V
$V_{\text{BE(on)}}$	Base-Emitter On Voltage	$V_{\text{CE}} = -4\text{V}, I_C = -10\text{A}$			- 3	V
t_{D}	Delay Time	$V_{\text{CC}} = -30\text{V}, I_C = -5\text{A}$ $I_{\text{B1}} = -20\text{mA}, I_{\text{B2}} = 20\text{mA}$ $R_L = 6\Omega$		0.15		μs
t_{R}	Rise Time			0.55		μs
t_{STG}	Storage Time			2.5		μs
t_{F}	Fall Time			2.5		μs

* Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$

Typical Performance Characteristics

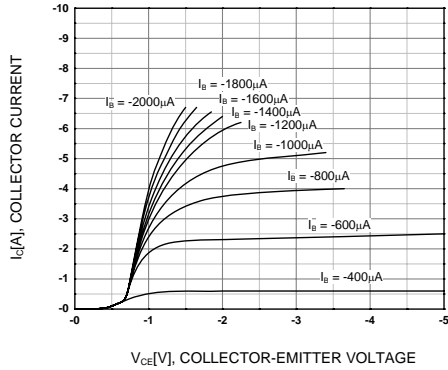


Figure 1. Static Characteristic

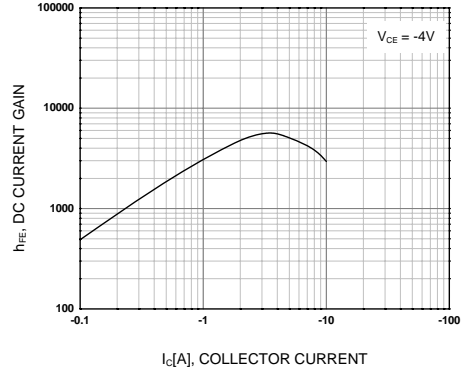


Figure 2. DC current Gain

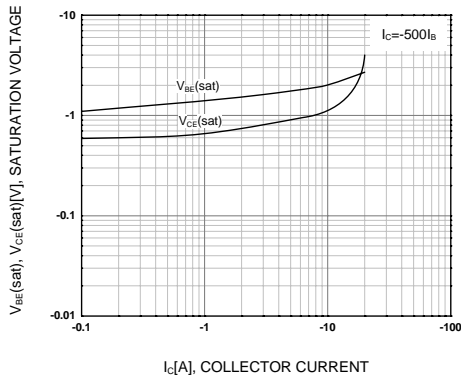


Figure 3. Collector-Emitter Saturation Voltage Base-Emitter Saturation Voltage

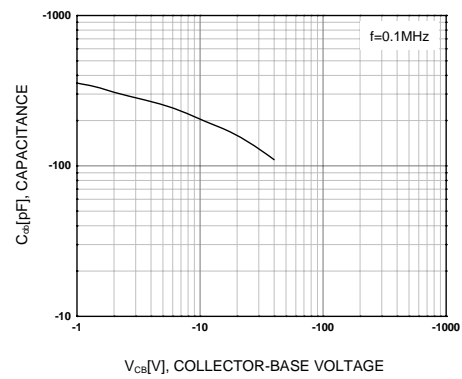


Figure 4. Collector Output Capacitance

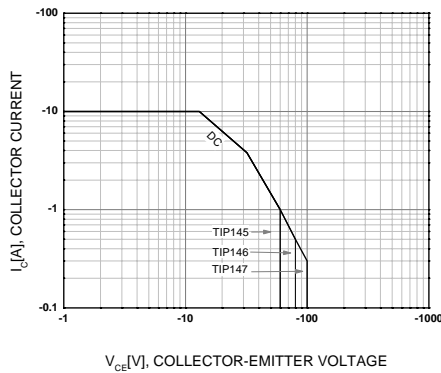


Figure 5. Safe Operating Area

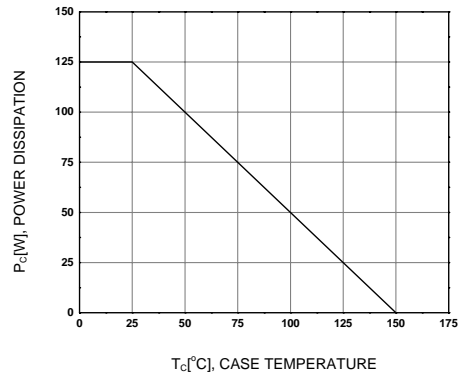
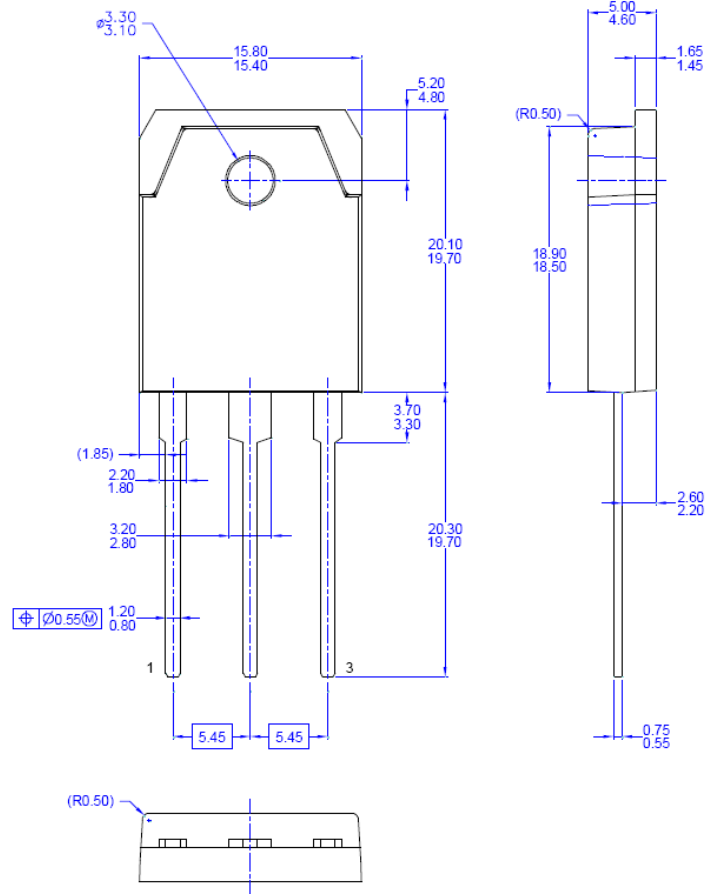


Figure 6. Power Derating

Physical Dimensions

TO-3P









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